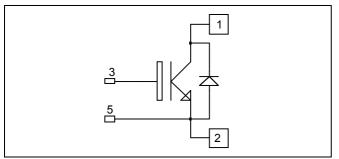
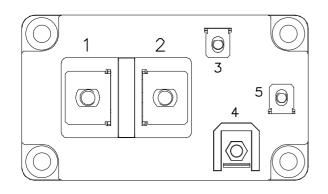


Single switch Trench + Field Stop IGBT3 Power Module





APTGT400U120D4G

$V_{CES} = 1200V$ $I_{C} = 400A$ @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- M6 connectors for power
- M4 connectors for signal
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Breakdown Voltage		1200	V
т	Continuous Collector Current	$T_C = 25^{\circ}C$	650	
I _C	Continuous Conector Current	$T_C = 80^{\circ}C$	400	Α
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	800	
V _{GE}	Gate – Emitter Voltage		±20	V
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1785	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A@1050V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				750	μA
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V
V _{CE(sat)}	Conector Emitter saturation voltage	$I_{\rm C} = 400 {\rm A}$ $T_{\rm j} = 125^{\circ} {\rm C}$		2.0		v	
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 12mA$		5.0	5.8	6.5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		28		
C _{oes}	Output Capacitance	$V_{CE} = 25V$		1.6		nF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz		1.2		
Q _G	Gate charge	V _{GE} =±15V, I _C =400A V _{CE} =600V		3.7		μC
T _{d(on)}	Turn-on Delay Time	Inductive Switching (25°C)		280		
T _r	Rise Time	$V_{GE} = \pm 15V$		90		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 400A$		550		ns
$T_{\rm f}$	Fall Time	$R_G = 1.8\Omega$		130		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C)		300		
Tr	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$		100		ns
T _{d(off)}	Turn-off Delay Time	$I_{\rm C} = 400 \text{A}$		650		
T _f	Fall Time	$R_G = 1.8\Omega$		180		
Eon	Turn on Energy	$\begin{array}{c} V_{GE} = \pm 15V \\ V_{Bus} = 600V \end{array} T_{j} = 125^{\circ}C \end{array}$		33		mJ
E _{off}	Turn off Energy	$\begin{array}{c} I_{C} = 400 A \\ R_{G} = 1.8 \Omega \end{array} \qquad T_{j} = 125^{\circ} C \end{array}$		59		1110
I _{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 900V$ $t_p \le 10\mu s$; $T_j = 125^{\circ}C$		1600		А

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I _{RRM}	Maximum Reverse Leakage Current	V _R =1200V	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$			750 1000	μΑ
I _F	DC Forward Current		$Tc = 80^{\circ}C$		400		А
$V_{\rm F}$	Diode Forward Voltage	$I_{\rm F} = 400 {\rm A}$ $V_{\rm GE} = 0 {\rm V}$	$T_j = 25^{\circ}C$		1.6	2.1	V
v F	Diode i of ward Voltage		$T_{i} = 125^{\circ}C$		1.6		v
t	Reverse Recovery Time		$T_j = 25^{\circ}C$		250		ns
t _{rr}		$T_j = 125^{\circ}C$		350		115	
0	Payara Pasayary Charge	$I_{\rm F} = 400 \text{A}$ $V_{\rm R} = 600 \text{V}$	$T_j = 25^{\circ}C$		40		чС
Q _{rr}	Reverse Recovery Charge	$v_R = 600 v$ di/dt =4000A/us	$T_{i} = 125^{\circ}C$		75		μC
Err	December December Frances		$T_j = 25^{\circ}C$		18		mJ
	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		34		mJ

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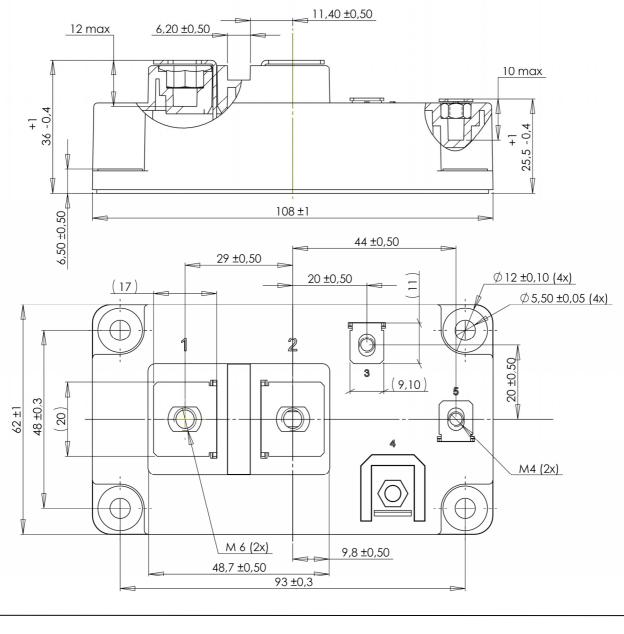


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Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R _{thJC}	Junction to Case Thermal Resistance	IGBT			0.07	°C/W	
R _{th} JC		Diode			0.13	C/ W	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
T _J	Operating junction temperature range		-40		150	5 °C	
T _{STG}	Storage Temperature Range		-40		125		
T _C	Operating Case Temperature		-40		125		
Torque	Mounting torque	M6	3		5	N.m	
		M4	1		2	19.111	
Wt	Package Weight				350	g	

D4 Package outline (dimensions in mm)



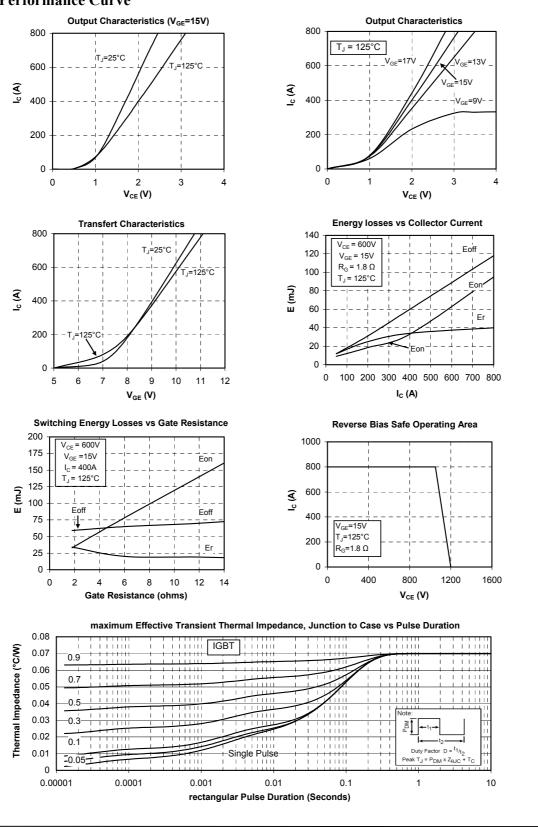
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Typical Performance Curve

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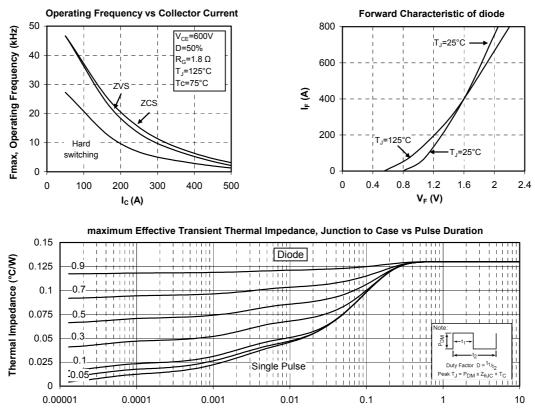


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rectangular Pulse Duration (Seconds)

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